



# NCE P-Channel Enhancement Mode Power MOSFET

## Description

The NCE40P40D uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge .This device is well suited for high current load applications.

#### **General Features**

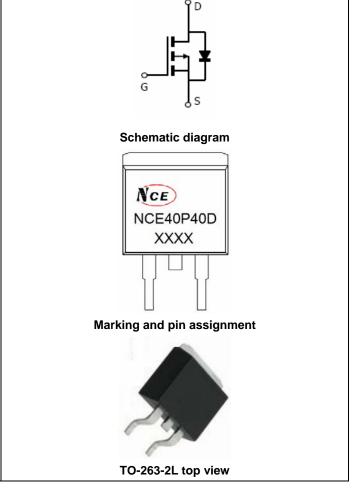
- V<sub>DS</sub> =-40V,I<sub>D</sub> =-40A
  R<sub>DS(ON)</sub> <14mΩ @ V<sub>GS</sub>=-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

#### 100% UIS TESTED!

**100% ΔVds TESTED!** 



## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE40P40D	NCE40P40D	TO-263-2L	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	-40	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	l <sub>D</sub> (100℃)	-25	A
Pulsed Drain Current	I <sub>DM</sub>	-120	A
Maximum Power Dissipation	PD	80	W
Derating factor		0.53	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	544	mJ
Operating Junction and Storage Temperature Range	$T_J,T_STG$	-55 To 175	്റ





### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	1.88	°C <b>/W</b>	]
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### Electrical Characteristics (T<sub>C</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-40	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V,V <sub>GS</sub> =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250µA	-1.5	-1.9	-3.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-12A	-	10	14	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-5V,I <sub>D</sub> =-12A	34	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	2960	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V, F=1.0MHz	-	370	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	-	310	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =-20V,I <sub>D</sub> =-20A	-	18	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =-10V,R <sub>G</sub> =3Ω	-	38	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	24	-	nS
Total Gate Charge	Qg	V = 20 L = 424	-	72		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-20,I <sub>D</sub> =-12A, V <sub>GS</sub> =-10V	-	14		nC
Gate-Drain Charge	Q <sub>gd</sub>	v <sub>GS</sub> 10v	-	15		nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-20A	-		-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-40	А
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =- 20A	-	40		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs <sup>(Note3)</sup>	-	42		nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LI				y LS+LD)

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t  $\leq$  10 sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- **5.** E<sub>AS</sub> condition: Tj=25  $^\circ C$  ,V<sub>DD</sub>=-20V,V<sub>G</sub>=-10V,L=1mH,Rg=25\Omega,I<sub>AS</sub>=33A

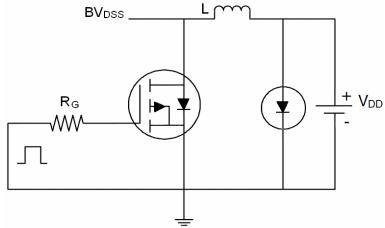


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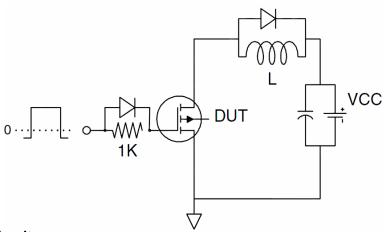
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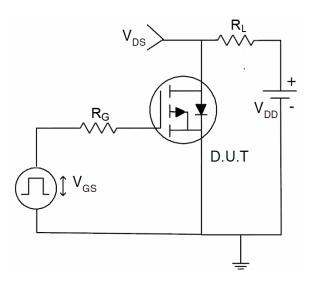
# Test Circuit 1) E<sub>AS</sub> Test Circuit



# 2) Gate Charge Test Circuit



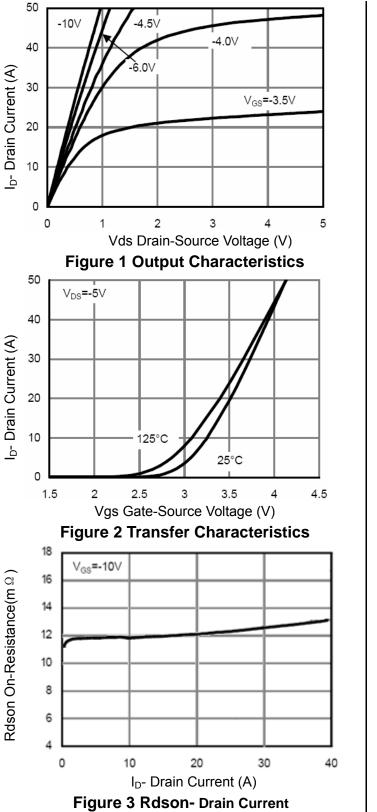
## 3) Switch Time Test Circuit

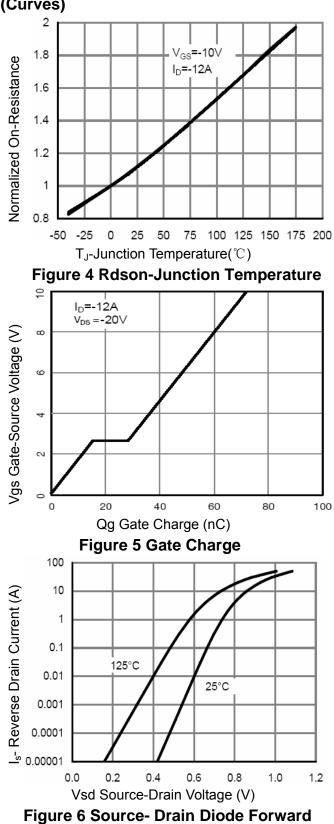








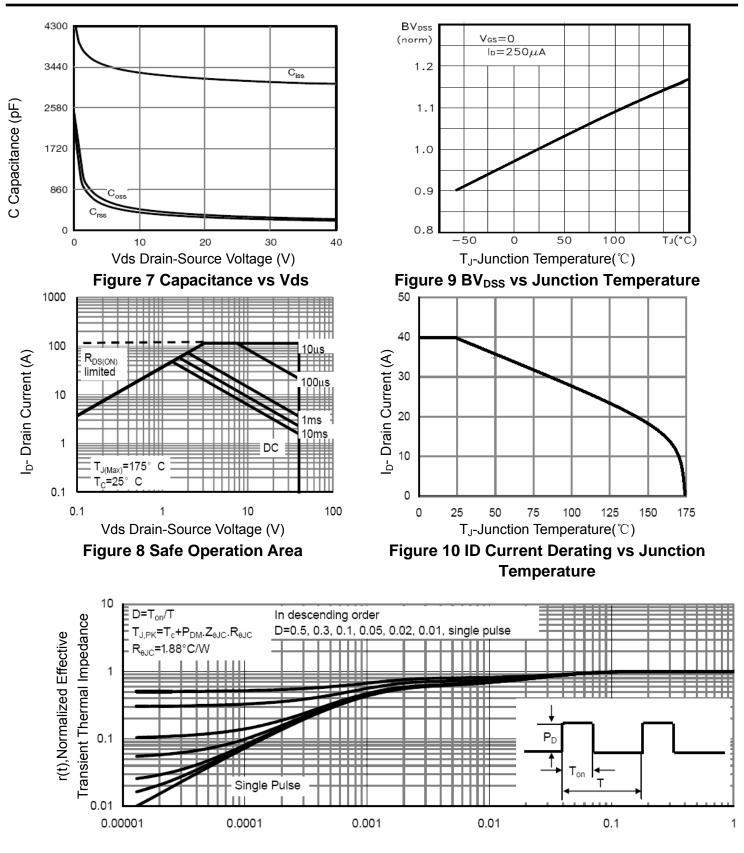






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NCE40P40D



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance

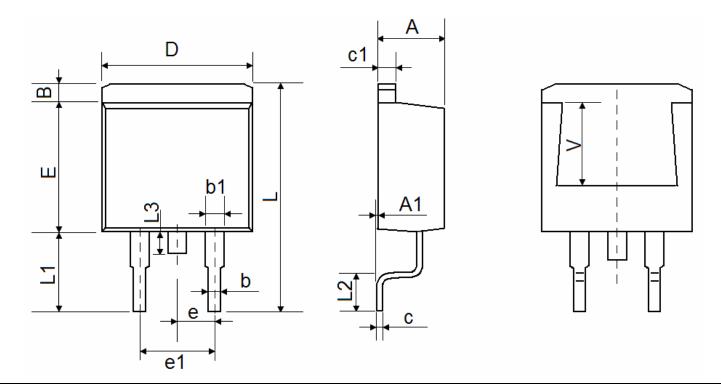


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# TO-263-2L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.170	1.370	0.046	0.054	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
L	15.050	15.450	0.593	0.608	
L1	5.080	5.480	0.200	0.216	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
V	5.600	0 REF	0.220 REF		







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